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Hibrit AlGaSb-Ar/H<sub>2</sub> mikro plazma sisteminde DC glow deşarjlarının modellenmesi ve simülasyonu

Modeling and simulation of DC glow discharges in the AlGaSb -coupled Ar/H<sub>2</sub> hybrid micro plasma system

Authors: Erhan ONGUN' Selçuk UJA޲, Hatice Hilal YÜCEL (KURT)³, Aybaba

HANÇERLİOĞULLARI⁴

ORCID<sup>1</sup>: 0009-0007-4966-1044

ORCID<sup>2</sup>: 0000-0002-9709-516X

ORCID3: 0000-0002-1277-5204

ORCID4: 0000-0001-9830-4226

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# Modeling and Simulation of DC Glow Discharges in the AlGaSb -coupled Ar/H<sub>2</sub> Hybrid Micro Plasma System

# Highlights

- Sub-atmospheric DC -driven microplasma—semiconductor hybrid system is simulated in 2D media.
- Spatiotemporal discharge dynamics are highly dependent on the cathode material and gas medium.
- ❖ GDSµPS cell can be regulated by hydrogen addition to argon discharge medium.

# **Graphical Abstract**

The numerical calculations reveal the spatiotemporal characteristics of 2D-modeled gas discharge-semiconductor microplasma system ( $GDS\mu PS$ ) as shown in figure below.

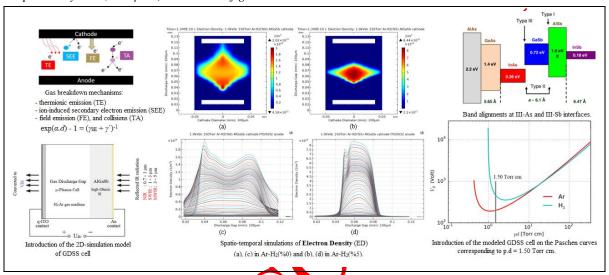


Figure. Introduction of the 2D-GDSµPS cell model and the spatiotemporal simulation results

# Aim

It is aimed to investigate the spatiotempokal discharge dynamics of DC -driven microplasma-semiconductor system with surface-modified (digitated) AlGaSb cashode -coupled Ar/H<sub>2</sub> gas medium.

# Design & Methodology

Numerical analyses of GDSµPS cell were carried out using FEM solver COMSOL Multiphysics program based on mixture-averaged diffusion-drip theory of gos discharges and Maxwellian electron energy distribution function.

# **Originality**

This study is an original research one to the simulation technique and the model solely used to investigate the spatiotemporal discharge characteristics of the 2D-GDSµPS cell, which is uniquely composed of digitated AlGaSb cathode coupled argon-hydrogen gas discharge medium.

# **Findings**

In the gas discharge medium of argon mixed with a molar fraction of 5% hydrogen compared to that of argon with no hydrogen addition, the operating point of GDS $\mu$ PS cell is shifted upward on the imaginary vertical projection line corresponding to 150 Torr.cm as shown on the Paschen curves while the electron energy appears to be denser and more localized across discharge gap of Ar/H<sub>2</sub>(%5) than that of Ar/H<sub>2</sub>(%0).

# Conclusion

It is concluded that cathode surface modification in microscale can be utilized as an effective design tool to manipulate the key discharge parameters. With hydrogen addition to argon medium, the operating characteristics of  $GDS\mu PS$  cell can be precisely regulated to respond the application-specific requirements.

# Declaration of Ethical Standards

The authors of this article declare that the materials and methods used in this study do not require ethical committee permission and/or legal-special permission.

# Modeling and Simulation of DC Glow Discharges in the AlGaSb -coupled Ar/H<sub>2</sub> Hybrid Micro Plasma System

Araştırma Makalesi / Research Article

Erhan ONGUN¹, Selçuk UTA޲, Hatice Hilal YÜCEL (KURT)³, Aybaba HANÇERLİOĞULLARI⁴\*

1.2.3\*Gazi University, Graduate School of Natural and Applied Sciences, Department of Physics,

Ankara, Türkiye

<sup>4</sup>Kastamonu University, Faculty of Arts and Sciences, Department of Physics, Kastamonu, Türkiye

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# **ABSTRACT**

Several studies have been reported on the theoretical and experimental investigation of gas discharge semiconductor microplasma systems ( $GDS\mu PS$ ).

In this study, a two-dimensional fluid model of a micro plasma in a square direct current (DCI glow-discharge chamber is simulated using the finite-element method (FEM) solver COMSOL Multiphysics program based on mixture-averaged diffusion-drift theory of gas discharges and Maxwellian electron energy distribution function.

A unique III-antimonide high-Ohmic semi-insulating aluminum gallium antimonide (AlGaSb) with finely digitated electron emission surface is modeled as planar cathode electrode coupled to ITO/SiO<sub>2</sub> planar acode electrode across a gas discharge gap of 100 µm distance. Argon (Ar) and argon mixed with a molar fraction of 5% hydrogen (Ar/H<sub>2</sub>) gas media are seperately introduced to the micro gap at sub-atmospheric pressure of 150 Torr, and the cell is driven at 1.0 kV DC by a stationary power source to simulate the transitions from electron field emission state to self-sustained normal slow discharge state.

simulate the transitions from electron field emission state to self-sustained normal glow discharge state.

The model is simulated to exhibit the transient physical characteristics of the AlGaSb-Ar/H<sub>2</sub> glow-discharge micro plasma system by solving the spatiotemporal dynamics of various discharge parameters including, electron density, electron energy density, electron current density and electric potential.

It has been observed that a fraction of hydrogen addition to argue can be used as an effective tool in modeling application-specific hybrid micro plasma—semiconductor based infrared photodetector devices.

Key words: Microplasma, AlGaSb, DC plasma simulation, infrared photodetector.

# Hibrit AlGaSb-Ar/H<sub>2</sub> Mikro Plazma Sisteminde DC Glow Desarjlarının Modellenmesi ve Simülasyonu

ÖZ

Bu çalışmada, mikro boşluku düziensel anot/katot elektrot plakalı atmosfer altı basınçta DC -beslemeli gaz deşarj-yarıiletken mikro plazma sistemlerin (GDSuPS) temel karakteristik özellikleri COMSOL Multifizik simülasyon platformunda incelendi. Modelde alüminyun gazyım antimonid (AlGaSb) katot elektrot, ITO/SiO2 anot elektrot, 100 µm gaz deşarj aralığına sahip mikro plazma hücresi modellendi. Plazma reaktör ortamında 150 Torr basınç seviyesinde argon (Ar) ve molar 5% hidrojen (H2) argon/hidrojen (Ar/H2) karışımı tanımlandı. Micro plazma hücresi 1.0 kV DC sabit gerilim altında beslendi. Model, elektron yoğunluğu, elektron enerji yoğunluğu, elektron akım yoğunluğu ve elektrik potansiyeli dahil olmak üzere çeşitli deşarj parametrelerinin uzaysal-zamansal dinamiklerini çözerek AlGaSb-Ar/H2 glow deşarj mikro plazma sisteminin geçiş fiziksel özelliklerini anlamak için simüle edildi. Uygulamaya özel hibrit mikro plazma—yarı iletken tabanlı kızılötesi fotodetektör cihazlarının modellenmesinde argona bir miktar hidrojen ilavesinin etkili bir araç olarak kullanılabileceği gözlemlenmiştir.

Anahtar Kelimeler: Mikroplazma, AlGaSb, DC plazma simülasyonu, kızılötesi fotodetektör.

# 1. INTRODUCTION

The emerging importance of microplasma devices in a wide variety of applications including, electric micropropulsion [1,2], microplasma thruster [3], microplasma materials [4], semiconductor gas discharge-based infrared converter systems [5, 6],

biomedical plasma applications in medicine [7,8] requires advanced characterization of the spatiotemporal discharge dynamics of plasma formation at the microscale.

Recent studies were reported on the theoretical and experimental investigation of planar DC field -driven gas discharge-semiconductor micro plasma systems (GDSµPS) [9-11] for modeling high-efficiency infrared-

\*Sorumlu Yazar (Corresponding Author) e-posta: aybaba@kastamonu.edu.tr to-visible image converters. An experimental study for self-sustaining DC glow discharges in air and neon gas media coupled with GaAs was reported at both sub- and atmospheric pressures [12]. Electro-optical analyzes of GaAs and GaP photocathode materials in the infrared detector applications have recently been studied [13]. An experimental investigation and a theoretical FEM analysis on electron density, electric potential and breakdown phenomena in a gas discharge medium consisting of air and helium coupled with InP photocathode material were reported [14]. Numerous theoretical and experimental research and development studies for advanced microplasma devices in diverse fields of science and engineering applications were reported [15-38].

In this study, a number of key operational characteristics of an exclusively-designed DC field -driven microplasma cell were broadly investigated in a 2D simulation platform based on mixture-averaged diffusion-drift theory of gas discharges and Maxwellian electron energy distribution function. The intended microplasma cell structure is basically built of a planar anode/cathode electrode pair, seperated by a gas discharge microgap, and coupled to a high-Ohmic semi-insulating aluminum gallium antimonide (AlGaSb) photocathode material with finely digitated planar electron emission surface. This novel bandgap-tunable infrared material was used in this simulation model due to its high response speed, high sensitivity and efficiency in producing photons in th atmospheric window from 3 µm to 5 µm wavelength range. Furthermore, Al-rich AlGaSb was reported to more chemically stable and resistant to oxidation than pure AlSb [39, 40]. Introducing the process gas medium in the proposed microplasma cell model in this study, argon was mixed with a maximum motar fraction of 5% hydrogen. The criteria, referred in determining the hydrogen ratio in the mixture, are primarily based on the safety issues that arise when working with hydrogen in the experimental setup, under the standard laboratory conditions as ignition can occur at a volumetric ratio of hydrogen to air as low as 4% due to its highest rating on the flammability scale. Thus, hydrogen ratio was limited at 5% in the mixture as a constant parameter, and the other key variable parameters of the model were manipulated. The effects of gas pressure on the spatiotemporal evolution of microplasma system were primarily studied in the range of 150 to 250 Torr. Process gas pressure of discharge medium was then set at 150 Torr in the proposed simulation model after several simulation trials, and also referring to the experimental results reported [41]. The electrical equivalent circuit of the cell was driven at 1.0 kV DC in order to simulate the transitions from field emission state to self-sustained normal glow gas discharge state.

Gas breakdown mechanism is governed by Townsend avalanche criterion in Equation 1.

$$\exp(\alpha.d) - 1 = \gamma_{SE}^{-1}$$
 (1) where:

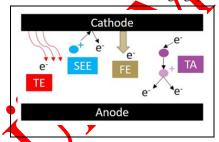
α: Ionization coeficient equal to the number of ions produced per electron in unit length.

d: Discharge gap length.

 $\gamma_{SE}$ : Secondary electron emission (SEE) coefficient, which quantifies the probability of electron emission from the cathode surface upon impact of cations.

Equation 1 reveals that SEE coefficient plays an important role in driving the breakdown mechanism. FEM solver-based spatiotemporal simulation can be a useful tool to predict gas discharge parameters and to perform transient analysis of the breakdown states.

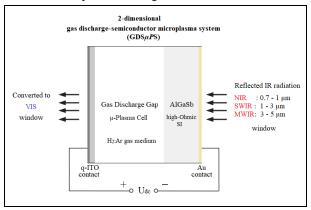
In Figure 1,  $\alpha$  ions are attracted to the cathode under high voltage, and upon impact, secondary electrons are ejected from the cathode surface to the discharge gap.



**Figure 1.** Gas breakdown mechanisms: Thermionic emission (TE), secondary electron emission (SEE), field emission (FE), Townsend avalanche (TA) [22].

Various computational and analytical solutions to these equations for gas breakdown mechanisms were used in recent review articles [11, 18, 19].

A basic 2D-model of GDS $\mu$ PS cell is introduced with its elemental components in Figure 2.

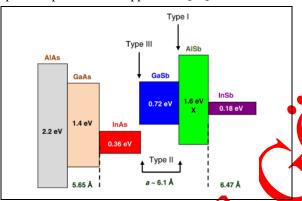


**Figure 2.** 2D-model of GDSμPS cell.

GDSμPS is principally designed to convert infrared (IR) light to visible (VIS) light in the cell. The incoming IR-light is efficiently absorbed by a wide-bandgap (III-V) and a high-Ohmic (specific resistance, ρ>E5 ohm.cm) semi-insulation cathode material. Electrons are liberated from grounded cathode electrode surface to the gas gap, and accelerated by positively-charged anode electrode. Highly energetic free electrons collide with ion molecules initiating the ionization reactions in the cell. Townsend avalanche (TA) mechanism leads to gas

breakdown state, and a normal glow discharge regime is self-sustained by passage of electron current across gas gap under infrared stimulation of photocathode electrode. A characteristic visible glow is emitted from the microplasma cell through a transparent-conductive (ITO) anode electrode.

antimonide (Sb) -rich III–V compound semiconductors, grown on GaSb or InAs substrates, include GaSb, InAs and AlSb binary compounds [23] with a wide band gap ranging from  $\sim 0.1$  to  $\sim 1.8$  eV. The diversity of accessible band alignments in III-Sb compounds is shown in Figure 3 [24] by which application-specific artificial materials with band gaps from near-infrared (NIR) to far-infrared (FIR) can be designed. The bandgap transitions of binary AlSb/GaSb alloys to ternary III-V compound Al<sub>x</sub>Ga<sub>1-x</sub>Sb alloys can be controlled between an indirect band gap AlSb semiconductor with Eg = 1.62 eV and a direct band gap GaSb semiconductor with Eg = 0.72 eV depending on the specific optoelectronic application [25].



**Figure 3**. Band alignments of III-As and III-St compounds. Scaled boxes represent band gaps of compounds upper and lower lines of conduction and valence bands respectively [25].

In Figure 4, a basic physical layout of the microplasma cell model is shown in quadrant region of the cylindrical coordinate system  $(r=x, \theta=0, z)$  in 2D.

In this simulation model, infrared transparent thin Au film -coated planar AlGaSo cathode with digitated electron emission surface was coupled across a gas discharge gap of 100 pm distance to thin ITO film -coated planar anode substrate of SiO<sub>2</sub> fused glass.

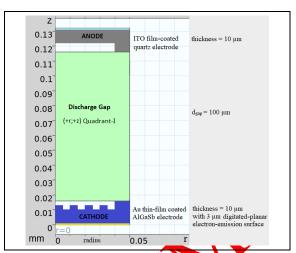


Figure 4. Physical layout of GDS uPS vell model in 2D.

The simulation studies were performed based on boundary-seperated mesh structure as shown in Figure 5.

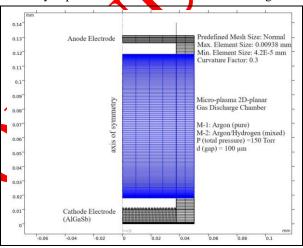


Figure 5. Mesh structure of GDSμPS cell model in 2D.

# 2. NUMERICAL ANALYSIS

A set of discharge parameters including, electron density (ED), electron energy density (EED), electron current density (ECD), and electric potential (EP) was studied using the COMSOL Multiphysics simulation program based on mixture-averaged diffusion-drift theory of gas discharges and Maxwellian electron energy distribution function.

In this study, the parameters and variables of GDS $\mu$ PS cell models were set as follows:

- i. Voltage supply to drive the cell: V=1.0 kV DC.
- ii. Plasma process gas types: Argon (Ar) and argon mixed with molar fraction of 5% hydrogen (Ar/H<sub>2</sub>).
- iii. Gas pressure: P=150 Torr.
- iv. Ambient cell operating temperature: T=300 K.
- v. Gas discharge gap length:  $d = 100 \mu m$ .
- vi. Cathode electrode: III-antimonide compound high-Ohmic semi-insulating aluminum gallium antimonide (AlGaSb) material.

vii. Modification of cathode electron emission surface: Finely digitated in the formation of 1.0  $\mu$ m height and 1.0  $\mu$ m width periodic squares of comb plate style.

viii. Cathode electrode width:  $w=100~\mu m$ , divided by a central symmetry axis in the 2D-model.

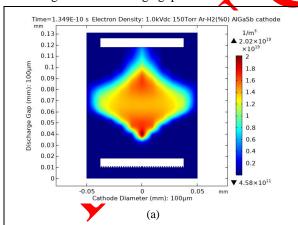
ix. Anode electrode: 1.0 µm thick ITO (In<sub>2</sub>O<sub>3</sub>-SnO<sub>2</sub> indium tin oxide) -coated fused glass (SiO<sub>2</sub>) substrate.

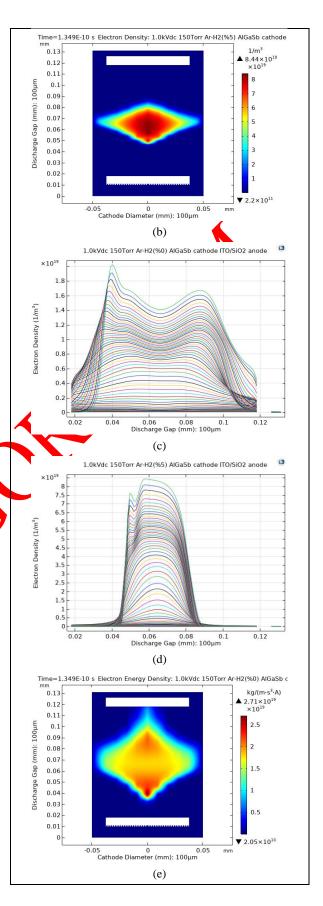
x. Initial electron density in the plasma reactor cell:  $n_{e,o}$ = 1.0E17 (1/m<sup>3</sup>).

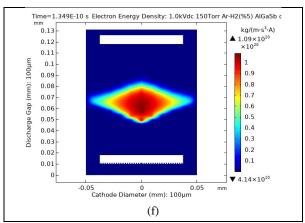
In the discharge model with binary argon-hydrogen gas medium, it is aimed to manipulate the operating point of GDS $\mu$ PS cell on the imaginary vertical projection line corresponding to P.d=1.50 Torr.cm in the Paschen curve.

# 3. RESULTS AND DISCUSION

Figure 6 (a) and (b) show 2D-images of spatiotemporal variation of Electron Density (ED) parameter calculated at final output time (t=1.349E-10s) of the plasma transition period, respectively for Ar/H<sub>2</sub>(%0) and Ar/H<sub>2</sub>(%5) gas media, and displayed in rainbowclassic color range across discharge gap. Figure 6 (c) and (d) show 1D-images of spatiotemporal variation of Electron Density (ED) parameter calculated at full output time range respectively for Ar/H<sub>2</sub>(%0) and Ar/H<sub>2</sub>(%5) gas media, and plotted as curves across discharge gap. Figure 6 (e) and (f) show 2D-images of spatiotemporal variation of Electron Energy Density (EED) parameter calculated at final output time respectively for Ar/H<sub>2</sub>(%0) ap Ar/H<sub>2</sub>(%5) gas media, and displayed in rainbowclassic color range across discharge gap.

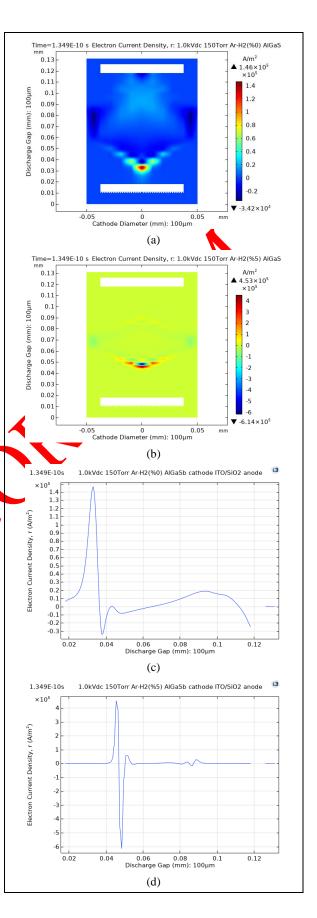


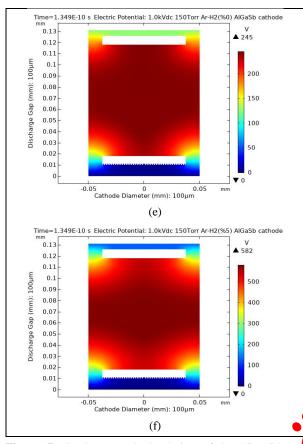




**Figure 6.** Spatiotemporal simulation of 2D-GDS $\mu$ PS cell model: (a) 2D image of Electron Density (ED) in Ar/H<sub>2</sub>(%0) at final output time (t=1.349E-10s) of the plasma transition period, (b) 2D image of Electron Density (ED) in Ar/H<sub>2</sub>(%5) at final output time (t=1.349E-10s) of the plasma transition period, (c) 1D plot of Electron Density (ED) in Ar/H<sub>2</sub>(%0) at full output times, (d) 1D plot of Electron Density (ED) in Ar/H<sub>2</sub>(%5) at full output times, (e) 2D image of Electron Energy Density (EED) in Ar/H<sub>2</sub>(%0) at final output time (t=1.349E-10s) of the plasma transition period, (f) 2D image of Electron Energy Density (EED) in Ar/H<sub>2</sub>(%5) at final output time (t=1.349E-10s) of the plasma transition period.

Figure 7 (a) and (b) show 2D-images of spatiotemporal variation of Electron Current Density (ECD) parameter calculated at final output time (t=1.349E-10s) of the plasma transition period, respectively for Ar/H2(%0) and Ar/H<sub>2</sub>(%5) gas media, and displayed in rainbowclassic color range across discharge gap. Figure (c) and (d) show 1D-images of spatiotemporal variation of Electron Current Density (ECD) parameter calculated at final output time respectively for  $Ar/H_2(\%0)$  and  $Ar/H_2(\%5)$ gas media, and plotted as single curve across discharge gap. Figure 🖪 (e) and (f) show 2D-images of spatiotemporal variation of Electric Potential (EP) parameter calculated at final output time respectively for Ar/H<sub>2</sub>(%0) and Ar/H<sub>2</sub>(%5) gas media, and displayed in rainbowclassic color range across discharge gap.





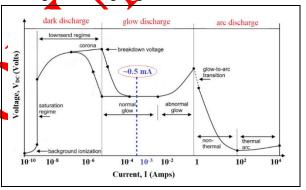
**Figure 7.** Spatiotemporal simulation of 2D-GDSμPS celmodel: (a) 2D image of Electron Current Density in Ar/H<sub>2</sub>(%0) at final output time (t=1.349E-10s) of the plasma transition period, (b) 2D image of Electron Current Density in Ar/H<sub>2</sub>(%5) at final output time (t=1.349E-10s) of the plasma transition period, (c) 1D plot of Electron Current Density in Ar/H<sub>2</sub>(%0) at final output time (t=1.349E-10s) of the plasma transition period, (d) 1D plot of Electron Current Density in Ar/H<sub>2</sub>(%5) at final output time (t=1.349E-10s) of the plasma transition period, (e) 2D image of Electric Potential in Ar/H<sub>2</sub>(%0) at final output time (t=1.349E-10s) of the plasma transition period, (f) 2D image of Electric Potential in Ar/H<sub>2</sub>(%5) at final output time (t=1.349E-10s) of the plasma transition period.

- ❖ Simulation results based on findings from Figure 6:
- The peak electron density (ED), calculated at final output time (t=1.3.9E-10s) of the plasma transition period, is higher (approximately x4 times) as displayed in Fig. 6(b) with  $Ar/H_2(\%5)$  than in Fig. 6(a) with  $Ar/H_2(\%0)$ .
- The electron density (ED) distribution, calculated at full output time range, is more localized across discharge gap as displayed in Fig. 6(d) with  $Ar/H_2(\%5)$  than in Fig. 6(c) with  $Ar/H_2(\%0)$ .
- The peak electron energy density (EED), calculated at final output time (t=1.349E-10s) of the plasma transition period, is higher and more localized across discharge gap as displayed in Fig. 6(f) with  $Ar/H_2(\%5)$  than in Fig. 6(e) with  $Ar/H_2(\%0)$ .
- ❖ Simulation results based on findings from Figure 7:

- The peak electron current density (ECD), calculated at final output time (t=1.349E-10s) of the plasma transition period, is higher (approximately x3 times) as displayed in Fig. 7(b) with  $Ar/H_2(\%5)$  than in Fig. 7(a) with  $Ar/H_2(\%0)$ .
- The electron current density (ECD) distribution, calculated at final output time (t=1.349E-10s) of the plasma transition period, is more localized across discharge gap as displayed in Fig. 7(d) with  $Ar/H_2(\%5)$  than in Fig. 7(c) with  $Ar/H_2(\%0)$ .
- The peak electric potential (EP), calculated at final output time (t=1.349E-10s) of the plasma transition period, is higher in value and more localized across discharge gap as displayed in Fig. 7(f) with  $Ar/H_2(\%5)$  at 582 Vdc than in Fig. 7(e) with  $Ar/H_2(\%0)$  at 245 Vdc.

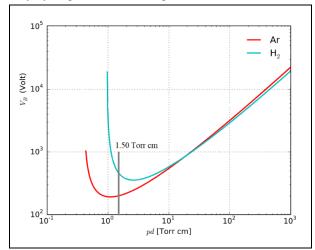
Figure 8 introduces the LV characteristics of gas discharges including, dark discharge, glow discharge and arc discharge regimes [28, 29].

The operating point of GDS $\mu$ PS cell model, simulated in this study, is indicated by dashed vertical line in blue corresponding to an estimated current of  $\sim 0.5$  mA in the normal glow discharge regime.



**Figure 8**. I-V characteristics of gas discharges including, dark discharge, glow discharge and arc discharge regimes [28, 29].

Figure 9 shows Paschen curves for argon and hydrogen gases [29]. It is aimed to locate the operating point of GDS $\mu$ PS cell on the imaginary vertical projection line corresponding to P.d = 1.50 Torr.cm, and to manipulate it by hydrogen addition to argon.



**Figure 9.** Paschen curves for argon and hydrogen gases [29]. The operating point of GDS $\mu$ PS cell is located on the imaginary vertical projection line corresponding to P.d = 1.50 Torr.cm.

### 4. CONCLUSIONS

It is concluded that hydrogen addition to argon can be used as an effective design tool to control the operating point of GDS $\mu$ PS cell for the dedicated application.

Numerical analysis results are reported as follows:

By hydrogen addition to argon, the operating point of the proposed GDSµPS cell model can be controlled on the imaginary vertical projection line corresponding to P.d=1.50 Torr.cm in the Paschen curve.

The calculated electric potential (EP) at final output time (t=1.349E-10s) of the plasma transition period peaks at 582 Vdc in the binary  $Ar/H_2(\%5)$  gas model and peaks at 245 Vdc in the unary Ar gas model.

The calculated peak electron density (ED) at final output time (t=1.349E-10s) of the plasma transition period is approximately four times higher in the binary  $Ar/H_2(\%5)$  gas model than in the unary Ar gas model.

The calculated peak electron current density (ECD) at final output time (t=1.349E-10s) of the plasma transition period is approximately three times higher in the binary Ar/H<sub>2</sub>(%5) gas model than in the unary Ar gas model.

Electron density (ED), electron current density (ECD) and electron energy density (EED) distribution patterns are highly localized across discharge gap in the bhary Ar/H<sub>2</sub>(%5) gas model than in the unary Ar gas model at final output time (t=1.349E-10s) of the plasma transition period.

The operating point of GDS $\mu$ PS cell model ocates in the normal glow discharge regime at an estimated current rating of  $\sim 0.5$  mA as calculated.

It is figured out that the binary Ar/H<sub>2</sub> has discharge model can undertake a major role in shaping and controlling the spatiotemporal response to transient electro-optical behavior of microplasma-based artificial electromagnetic materials configured for high-efficiency infrared-to-visible wavelength conversion applications [42-44].

# Symbols and Abbreviations

Ar: Argon H<sub>2</sub>:Hydrogen Au: Gold

ITO: Indium Tin Oxide SiO<sub>2</sub>:Silicon Dioxide, Silica

AlGaSb: Aluminum Gallium Antimonide

GDSµPS: Gas Gischarge-Semiconductor Microplasma

System

FEM: Finite Element Method

DC: Direct Current I-V: Current-Voltage

SEE: Secondary Electron Emission

TE: Thermionic Emission FE: Field Emission

TA: Townsend Avalanche

VIS: Visible

NIR: Near-infrared

SWIR: Short-wave infrared MWIR: Mid-wave infrared

FIR: Far-infrared ED: Electron Density

EED: Electron Energy Density

ECD,r: Electron Current Density (r-component)

EP: Electric Potential.

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# DECLARATION OF ETHICAL STANDARDS

The authors of this article declare that the materials and methods used in this study do not require ethical committee permission and or legal-special permission.

# **AUTHORS' CONTRIBUTIONS**

Erhan ONGUN: Modeling, simulation, article writing. Selvuk LTAS: Modeling, simulation.

**Prof. Dr. Hatice Hilal YÜCEL (KURT):** Supervisor of ONCUN's doctoral thesis, expert on the plasma science and technology, article writing and editing.

**Prof. Dr. Aybaba HANÇERLİOĞULLARI:** Member of ONGUN's doctoral thesis monitoring committee.

# CONFLICT OF INTEREST

There is no conflict of interest in this study.

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